

PMP4501Y,135 Datasheet





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DiGi Electronics Part Number PMP4501Y,135-DG

Manufacturer Nexperia USA Inc.

Manufacturer Product Number PMP4501Y,135

Description TRANS 2NPN 45V 0.1A 6TSSOP

Detailed Description Bipolar (BJT) Transistor Array 2 NPN (Dual) Matched

Pair 45V 100mA 250MHz 300mW Surface Mount 6-

TSSOP



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Manufacturer Product Number:	Manufacturer:
PMP4501Y,135	Nexperia USA Inc.
Series:	Product Status:
	Active
Transistor Type:	Current - Collector (Ic) (Max):
2 NPN (Dual) Matched Pair	100mA
Voltage - Collector Emitter Breakdown (Max):	Vce Saturation (Max) @ lb, Ic:
45V	400mV @ 5mA, 100mA
Current - Collector Cutoff (Max):	DC Current Gain (hFE) (Min) @ Ic, Vce:
15nA (ICBO)	200 @ 2mA, 5V
Power - Max:	Frequency - Transition:
300mW	250MHz
Operating Temperature:	Grade:
150°C (TJ)	Automotive
Qualification:	Mounting Type:
AEC-Q100	Surface Mount
Package / Case:	Supplier Device Package:
6-TSSOP, SC-88, SOT-363	6-TSSOP
Base Product Number:	
PMP4501	

Environmental & Export classification

8541.21.0075

RoHS Status:	Moisture Sensitivity Level (MSL):
ROHS3 Compliant	1 (Unlimited)
REACH Status:	ECCN:
REACH Unaffected	EAR99
HTSUS:	



PMP4501Y

45 V, 100 mA NPN/NPN matched double transistor

28 December 2022

Product data sheet

1. General description

NPN/NPN matched double transistor in a very small Surface-Mounted Device (SMD) SOT363 (SC-88) plastic package. The transistors in the SOT363 package are fully isolated internally.

NPN/NPN hFE1/hFE2 0.98 complement: PMP4201Y

PNP/PNP complement: PMP5501Y

2. Features and benefits

- Current gain matching
- Base-emitter voltage matching
- Application-optimized pinout
- AEC-Q101 qualified

3. Applications

- Current mirror
- · Differential amplifier

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transistor					<u>'</u>		
V _{CEO}	collector-emitter voltage	open base		-	-	45	V
I _C	collector current			-	-	100	mA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C		200	290	450	
Per device							
h _{FE1} /h _{FE2}	DC current gain matching	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$	[1]	0.95	1	-	
V _{BE1} -V _{BE2}	base-emitter voltage matching		[2]	-	-	2	mV

^[1] The smaller of the two values is taken as the numerator.



^[2] The smaller of the two values is subtracted from the larger value.

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	B1	base TR1		04 54 50
2	B2	base TR2	6 5 4	C1 E1 E2
3	C2	collector TR2		TR2
4	E2	emitter TR2		
5	E1	emitter TR1	☐1 ☐2 ☐3	B1 B2 C2 006aaa548
6	C1	collector TR1	TSSOP6 (SOT363)	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PMP4501Y		plastic, surface-mounted package; 6 leads; 0.65 mm pitch; 2.1 mm x 1.25 mm x 0.95 mm body	<u>SOT363</u>

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PMP4501Y	S8%

^{[1] % =} placeholder for manufacturing site code

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
Per transisto	or					
V_{CBO}	collector-base voltage	open emitter		-	50	V
V_{CEO}	collector-emitter voltage	open base		-	45	V
V _{EBO}	emitter-base voltage	open collector		-	6	V
Ic	collector current			-	100	mA
I _{CM}	peak collector current	t _p ≤ 1 ms		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	200	mW
Per device	·		·			
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	300	mW
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transist	or		,				
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	625	K/W
Per device			,			'	
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	[1]	-	-	416	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Per transisto	r						'
I _{CBO}	collector-base cut-off	V _{CB} = 30 V; I _E = 0 A; T _{amb} = 25 °C		-	-	15	nA
	collector-base cut-off current emitter-base cut-off current DC current gain collector-emitter saturation voltage base-emitter voltage base-emitter voltage collector capacitance emitter capacitance transition frequency noise figure DC current gain matching base-emitter voltage	V _{CB} = 30 V; I _E = 0 A; T _j = 150 °C		-	-	5	μA
I _{EBO}		V _{EB} = 5 V; I _C = 0 A; T _{amb} = 25 °C		-	-	100	nA
h _{FE}	DC current gain	V _{CE} = 5 V; I _C = 10 μA; T _{amb} = 25 °C		-	250	-	
		V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C		200	290	450	
V _{CEsat}		I_C = 10 mA; I_B = 0.5 mA; T_{amb} = 25 °C		-	50	200	mV
	saturation voltage	I _C = 100 mA; I _B = 5 mA; T _{amb} = 25 °C		-	200	400	mV
V _{BEsat}	base-emitter saturation	I_C = 10 mA; I_B = 0.5 mA; T_{amb} = 25 °C	[1]	-	760	-	mV
	voltage	I _C = 100 mA; I _B = 5 mA; T _{amb} = 25 °C	[1]	-	910	-	mV
V _{BE} b	base-emitter voltage	V _{CE} = 5 V; I _C = 2 mA; T _{amb} = 25 °C	[2]	610	660	710	mV
		V _{CE} = 5 V; I _C = 10 mA; T _{amb} = 25 °C	[2]	-	-	770	mV
C _c	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A}; f = 1 \text{ MHz}; $ $T_{amb} = 25 \text{ °C}$		-	-	1.5	pF
C _e	emitter capacitance	$V_{EB} = 0.5 \text{ V}; I_{C} = 0 \text{ A}; i_{c} = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 ^{\circ}\text{C}$		-	11	-	pF
f _T	transition frequency	V_{CE} = 5 V; I_{C} = 10 mA; f = 100 MHz; T_{amb} = 25 °C		100	250	-	MHz
NF	noise figure	V_{CE} = 5 V; I_{C} = 0.2 mA; R_{S} = 2 k Ω ; f = 10 Hz to 15.7 kHz; T_{amb} = 25 °C		-	2.8	-	dB
		V_{CE} = 5 V; I_{C} = 0.2 mA; R_{S} = 2 k Ω ; B = 200 Hz; f = 1 kHz; T_{amb} = 25 °C		-	3.3	-	dB
Per device	·			·			
h _{FE1} /h _{FE2}	<u> </u>	$V_{CE} = 5 \text{ V}; I_{C} = 2 \text{ mA}; T_{amb} = 25 \text{ °C}$	[3]	0.95	1	-	
V _{BE1} -V _{BE2}	base-emitter voltage matching		[4]	-	-	2	mV

^[1] V_{BEsat} decreases by about 1.7 mV/K with increasing temperature.

^[2] V_{BE} decreases by about 2 mV/K with increasing temperature.

^[3] The smaller of the two values is taken as the numerator.

^[4] The smaller of the two values is subtracted from the larger value.

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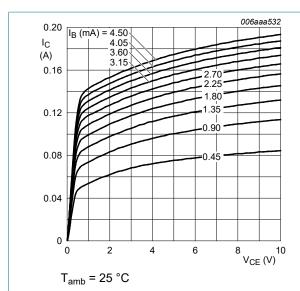
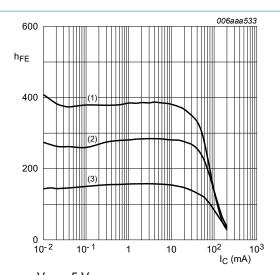
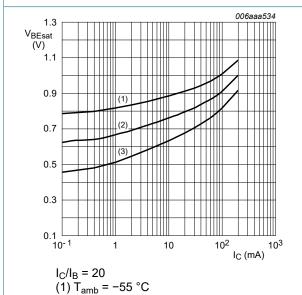


Fig. 1. Collector current as a function of collectoremitter voltage; typical values



 $V_{CE} = 5 \text{ V}$ (1) $T_{amb} = 100 \,^{\circ}\text{C}$ (2) $T_{amb} = 25 \,^{\circ}\text{C}$ (3) $T_{amb} = -55 \,^{\circ}\text{C}$

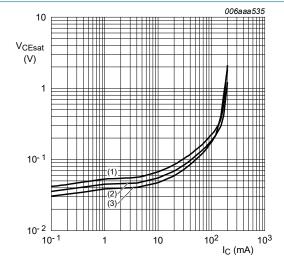
Fig. 2. DC current gain as a function of collector current; typical values



(3) T_{amb} = 100 °C

Fig. 3. Base-emitter saturation voltage as a function of collector current; typical values

(2) T_{amb} = 25 °C



 $I_{C}/I_{B} = 20$ (1) $T_{amb} = 100 \,^{\circ}C$ (2) $T_{amb} = 25 \,^{\circ}C$ (3) $T_{amb} = -55 \,^{\circ}C$

Fig. 4. Collector-emitter saturation voltage as a function of collector current; typical values

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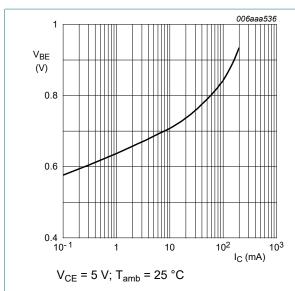


Fig. 5. Base-emitter voltage as a function of collector current; typical values

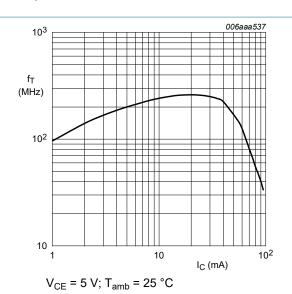


Fig. 6. Transition frequency as a function of collector current; typical values

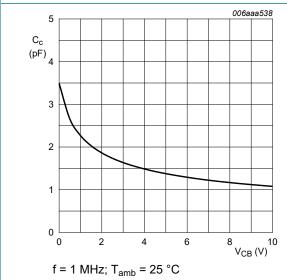
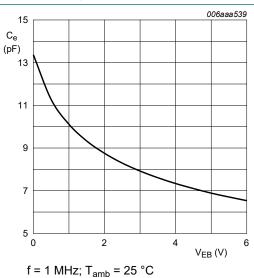
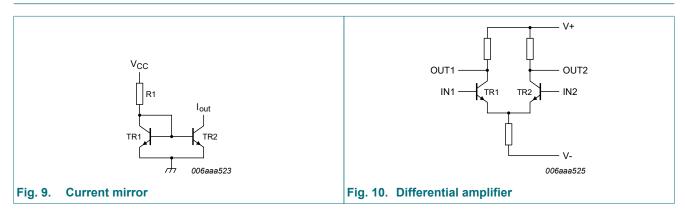


Fig. 7. Collector capacitance as a function of collectorbase voltage; typical values



8. Emitter capacitance as a function of emitterbase voltage; typical values

11. Application information



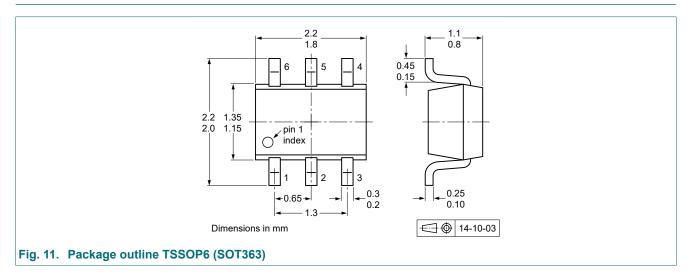
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12. Test information

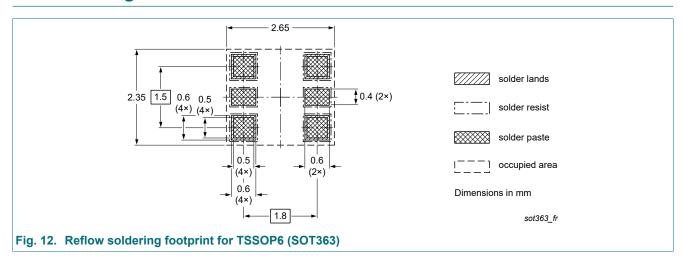
Quality information

This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - *Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

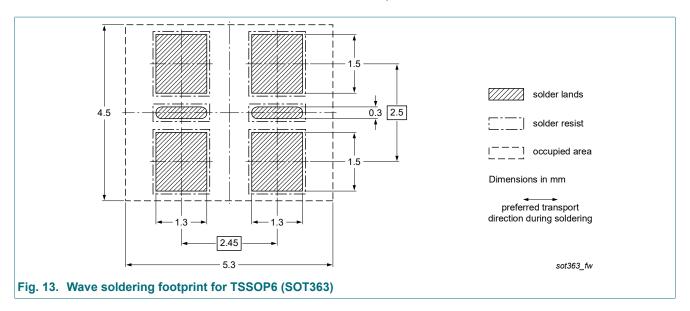
13. Package outline



14. Soldering



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15. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMP4501Y v.5	20221228	Product data sheet	-	PMP4501V_G_Y_4
Modifications:	Nexperia.	s data sheet has been rede been adapted to the new c ion removed.		, ,
PMP4501V_G_Y_4	20090828	Product data sheet	-	PMP4501V_G_Y_3
PMP4501V_G_Y_3	20060919	Product data sheet	-	PMP4501G_Y_2
PMP4501G_Y_2	20060214	Product data sheet	-	PMP4501G_Y_1
PMP4501G_Y_1	20060202	Product data sheet	-	-

16. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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